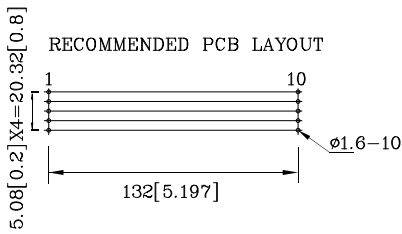
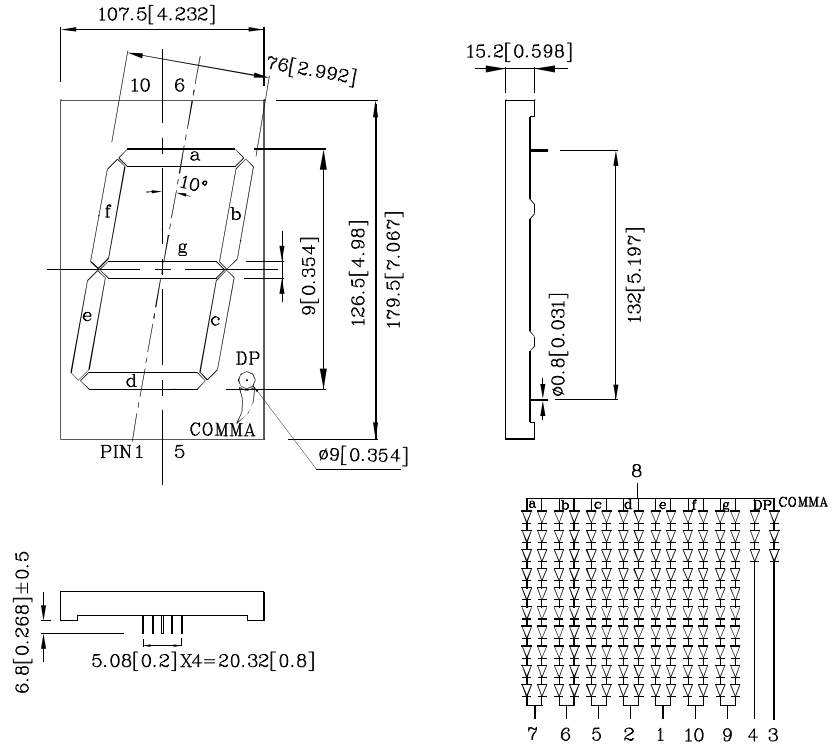


**Features**

- Low power consumption
- Robust package
- I.C. Compatible
- Standard configuration: Gray face w/ white segments
- Optional black face provides superior color contrast
- RoHS Compliant



**Package Schematics**



**Notes:**

1. All dimensions are in millimeters (inches), Tolerance is ±0.25(0.01") unless otherwise noted.
2. Specifications are subject to change without notice.

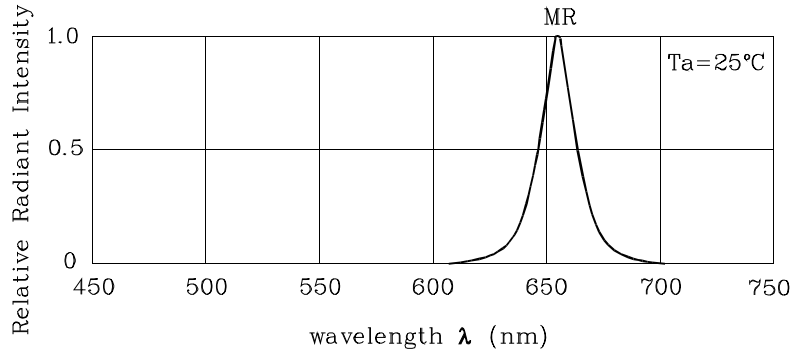
Absolute Maximum Ratings (T <sub>A</sub> =25°C)	MR (GaAlAs)	Unit
Reverse Voltage Per Segment Or (Dp And Comma)	V <sub>R</sub> 5 (5)	V
DC Forward Current Per Segment Or (Dp And Comma)	I <sub>F</sub> 60 (30)	mA
Forward Current (Peak) Per Segment Or (Dp And Comma) 1/10 Duty Cycle 0.1ms Pulse Width	i <sub>FS</sub> 310 (155)	mA
Power Dissipation Per Segment Or (Dp And Comma)	P <sub>D</sub> 1500 (225)	mW
Operating Temperature	T <sub>A</sub> -40 ~ +85	°C
Storage Temperature	T <sub>stg</sub> -40 ~ +85	
Lead Solder Temperature [2mm Below Package Base]	260°C For 3-5 Seconds	

Operating Characteristics (T <sub>A</sub> =25°C)	MR (GaAlAs)	Unit
Forward Voltage (Typ.) (I <sub>F</sub> =10mA) Per Segment Or (Dp And Comma)	V <sub>F</sub> 18 (5.4)	V
Forward Voltage (Max.) (I <sub>F</sub> =10mA) Per Segment Or (Dp And Comma)	V <sub>F</sub> 25 (7.5)	V
Reverse Current (V <sub>R</sub> =5V) (Max.) Per Segment Or (Dp And Comma)	I <sub>R</sub> 20 (10)	uA
Wavelength of Peak Emission CIE127-2007* (Typ.) (I <sub>F</sub> =10mA)	λ <sub>P</sub> 660 655*	nm
Wavelength of Dominant Emission CIE127-2007* (Typ.) (I <sub>F</sub> =10mA)	λ <sub>D</sub> 640 640*	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I <sub>F</sub> =10mA)	Δλ 20	nm
Capacitance (Typ.) (V <sub>F</sub> =0V, f=1MHz)	C 45	pF

Part Number	Emitting Color	Emitting Material	Luminous Intensity CIE127-2007* (I <sub>F</sub> =10mA) ucd	Wavelength CIE127-2007* nm λP	Description
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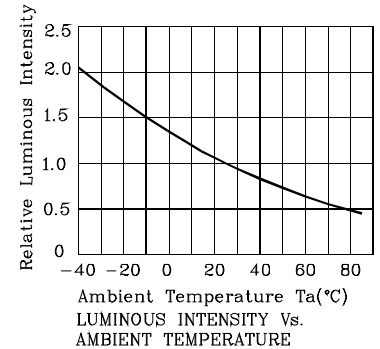
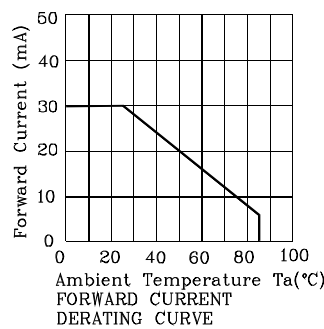
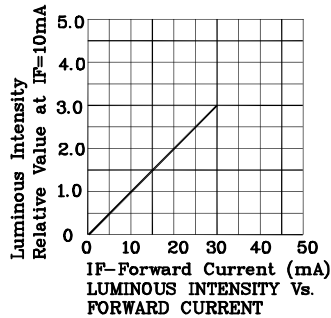
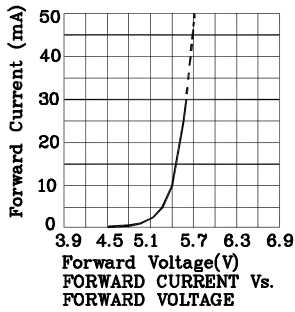
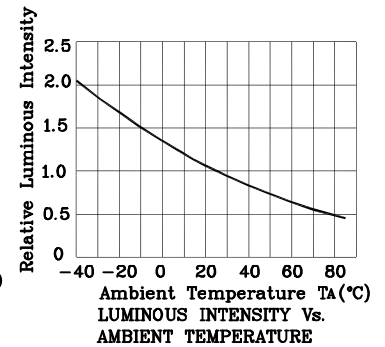
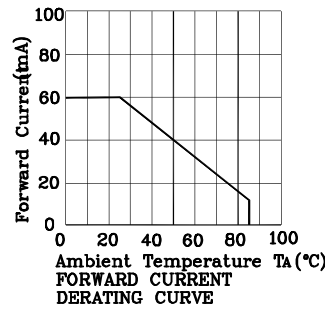
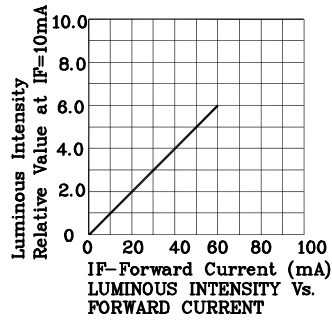
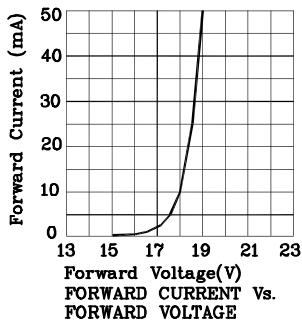
			min.	typ.	
XDMR127A-B	Red	GaAlAs	88000 21000*	169990 43000*	660 655*
					Common Anode, Rt.Hand Decimal.

\*Luminous intensity value and wavelength are in accordance with CIE127-2007 standards.  
Jul 06,2012

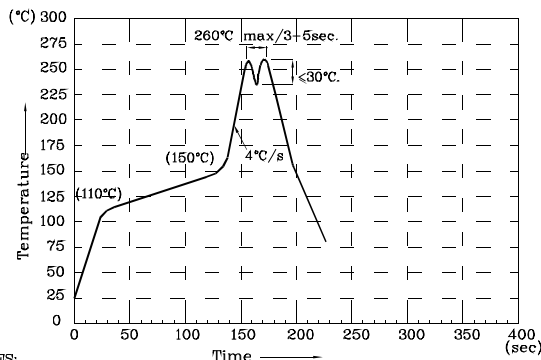


RELATIVE INTENSITY Vs. CIE WAVELENGTH

❖ MR



Wave Soldering Profile for Thru-Hole Products (Pb-Free Components)



NOTES:

1. Recommend the wave temperature 245°C~260°C. The maximum soldering temperature should be less than 260°C.
2. Do not apply stress on epoxy resins when temperature is over 85°C.
3. The soldering profile apply to the lead free soldering (Sn/Cu/Ag alloy).
4. During wave soldering, the PCB top-surface temperature should be kept below 105°C.
5. No more than once.

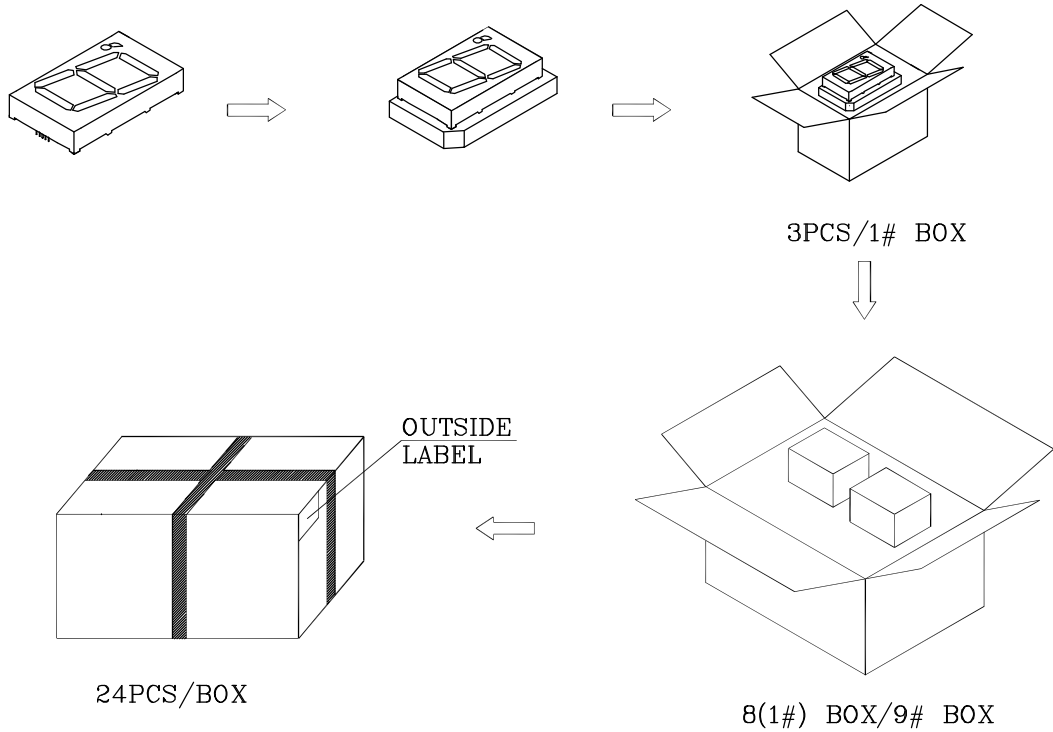
Remarks:

If special sorting is required (e.g. binning based on forward voltage, luminous intensity / luminous flux, or wavelength), the typical accuracy of the sorting process is as follows:

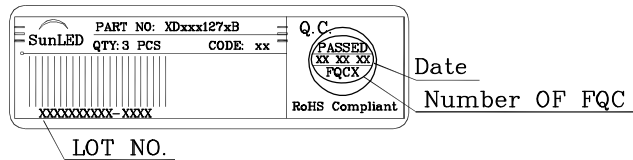
1. Wavelength:  $\pm 1\text{nm}$
2. Luminous Intensity / Luminous Flux:  $\pm 15\%$
3. Forward Voltage:  $\pm 0.1\text{V}$

Note: Accuracy may depend on the sorting parameters.

PACKING & LABEL SPECIFICATIONS



Inside Label On 1#BOX



Outside Label On Box

